

Application Data Sheet

Inventor Information

Inventor One Given Name:

Family Name:

Name Suffix:

Postal Address Line One

Postal Address Line Two

City:

State or Province: Postal or Zip Code:

Citizenship Country:

Inventor Two Given Name:

Family Name: Name Suffix:

Postal Address Line One Postal Address Line Two

City:

State or Province: Postal or Zip Code: Citizenship Country: Tetsuyoshi

INOUE

2-3-52-109, Nishimikurado

Yamatotakada-shi Nara-ken, Japan

Japan

Kazunori MATSUBARA

537, Yakuoji, Tawaramoto-cho,

Shiki-gun

Nara-ken, Japan

Correspondence Information

Name Line One:

Name Line Two:

Address Line One:

Address Line Two:

City:

State or Province:

Postal or Zip Code: Telephone:

Fax:

Electronic Mail:

Barry E. Bretschneider Morrison & Foerster LLP

2000 Pennsylvania Avenue, N.W.

Suite 5500

Washington DC

20006-1888

(202) 887-1545 (202) 263-8396

BBretschneider@mofo.com

Application Information

Title Line One: Title Line Two:

Total Drawing Sheets:

Formal Drawing Application Type: Docket Number:

SEMICONDUCTOR LASER MANUFACTURING METHOD AND SEMICONDUCTOR LASER

7 Yes Utility

204552021700

Representative Information

Representative Customer Number: 25227

Prior Foreign Applications

Foreign Application One:

Filing Date:

Country:
Priority Claimed:

2000-354191

November 21, 2000

Japan

Yes